

RED DIODE LASER AT 635nm

RN-III-635R/1~150mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy operation.

They are widely used in measurement, spectrum analysis, laser lighting show, etc.

产品参数

RN-III-635R/1~150mW					
Central wavelength (nm)	635±5	637±5	640±5		
Operating mode	CW				
Output power (mW)	>1,10,20,..., 200				
Power stability (rms, over 4 hours)	<1%, <2%, <3% (<0.5%, optional)				
Transverse mode	Near TEM ₀₀				
M2 factor	<1.5 (<1.2, optional)				
Beam diameter at the aperture (1/e ² ,mm)	~3.0 (~1.2, optional)				
Beam divergence, full angle (mrad)	<1.0				
Polarization ratio	>50:1 (>100:1, optional) Horizontal±5 degree (Vertical Optional)				
Warm-up time (minutes)	<5				
Pointing stability after warm-up (mrad)	<0.05				
Beam height from base plate (mm)	24. 8				
Operating temperature (°C)	10~35				
Power supply	85-264VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz)			
	100-240VAC	PSU-A-D (Frequency for 30kHz -100kHz)			
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional				
Expected lifetime (hours)	10000				
Warranty	1 year				



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